



Product Summarv

BV _{DSS}	R _{DS(ON)} MAX	Package	Ι _{D MAX} Τ _A = +25°C
-20V	110mΩ @ V _{GS} = -4.5V	SOT23	-2.6A
-200	$225m\Omega @ V_{GS} = -2.5V$		-2.0A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- **Power Management Functions**

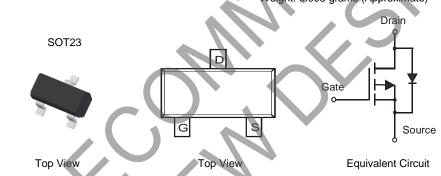
P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMP2225LQ)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



Ordering Information (Note 4)

Part Number	Qualification	Case	Packaging
DMP2225L-7	Standard	SOT23	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds. 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

2P2	ΜY

2P2 = Product Type Marking Code YM or $\overline{Y}M$ = Date Code Marking Y or \overline{Y} = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	2008		2009	~		2017	2018		2019	2020)	2021
Code	V		W	~		E	F		G	Н		
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



DMP2225L

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteri	stic		Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage		V _{GSS}	±12	V	
Continuous Drain Current (Note 5)	Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$		ID	-2.6 -2	А
Pulsed Drain Current (Note 6)		I _{DM}	-8	A	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.08	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	R _{θJA}	115	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

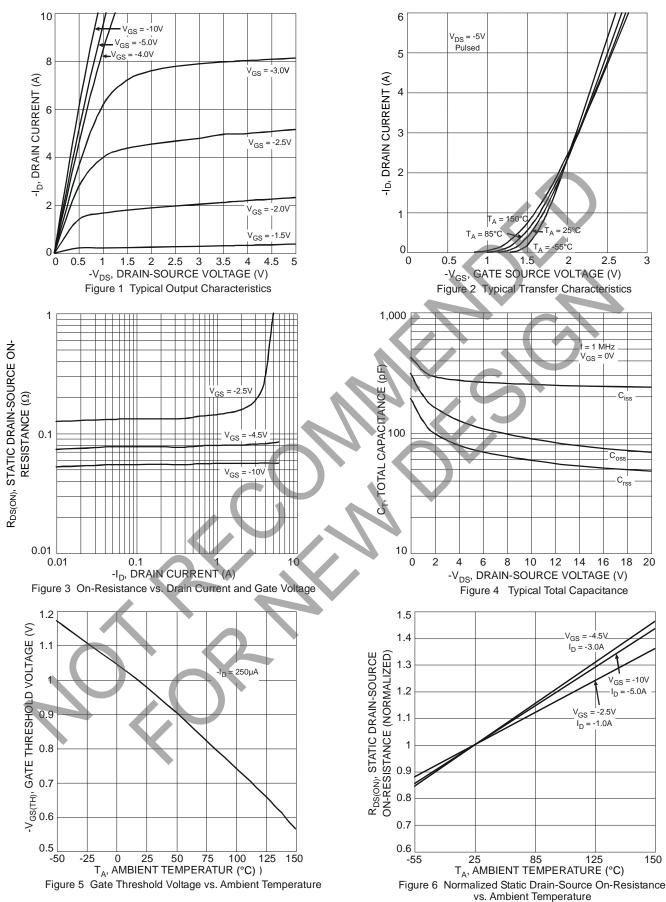
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	-20	—		V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current	I _{DSS}	—	• _	-800	nA	$V_{DS} = -20V, V_{GS} = 0V$
On-State Drain Current	ID(ON)	-6 -3			А	$V_{DS} \le -5V, V_{GS} = -4.5V$ $V_{DS} \le -5V, V_{GS} = -2.5V$
Gate-Source Leakage	IGSS			±80	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	-0.45	—	-1.25	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance			80	110	mΩ	$V_{GS} = -4.5V, I_D = -2.6A$
Static Dialit-Source Off-Resistance	RDS(ON)		165	225		$V_{GS} = -2.5V, I_D = -2.0A$
Forward Transfer Admittance	Y _{fs}	_	4	_	s	$V_{DS} = -5V, I_D = -2.6A$
Diode Forward Voltage (Note 6)	V _{SD}	_	_	-1.26	V	$V_{GS} = 0V, I_{S} = -2.6A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		250	_	pF	
Output Capacitance	Coss	—	88	_	рF	V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	58	—	pF	1 = 1.0MH2
Gate Resistance	Rg	—	12	16	Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$
Total Gate Charge	Qg	—	4.3	5.3		
Gate-Source Charge	Qgs	—	0.9	—	nC	$V_{GS} = -4.5V, V_{DS} = -10V,$
Gate-Drain Charge	Q _{gd}	_	2.1	—		I _D = -2.7A

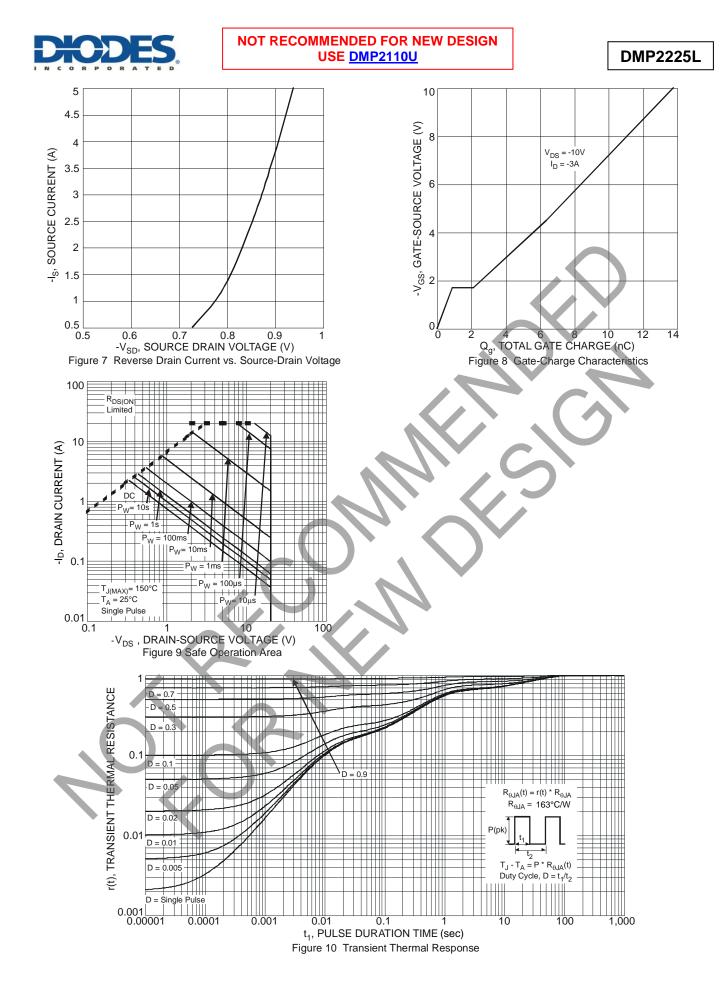
 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Repetitive rating, pulse width limited by junction temperature.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing. Notes:



NOT RECOMMENDED FOR NEW DESIGN USE <u>DMP2110U</u>

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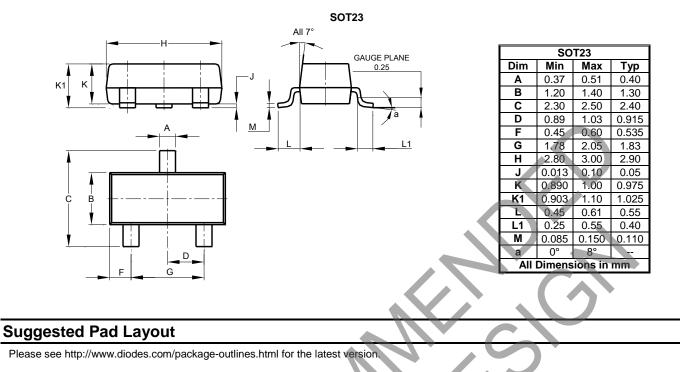


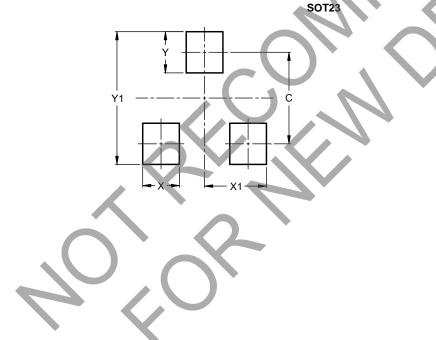




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



DMP2225L

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